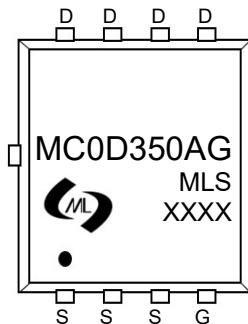


## Features

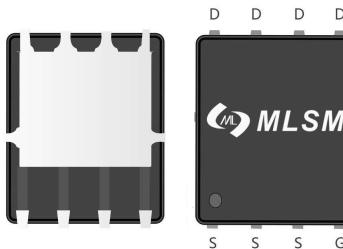
- Split gate trench MOSFET technology
- High density cell design for ultra low  $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## Application

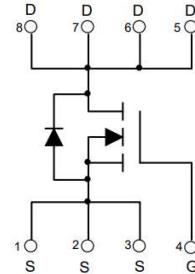
- High current load applications
- Load switch
- Hard switched and high frequency circuits



MC0C350AG: Device code  
XXXX : Code



PDFN5X6-8L view



Schematic diagram



Halogen-Free

Marking and pin assignment

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol   | Parameter                           | Rating     | Unit |
|--|-------------------------------------|------------|------|
| <b>Common Ratings (TC=25°C Unless Otherwise Noted)</b> |                                     |            |      |
| $V_{DS}$   | Drain-Source Breakdown Voltage      | 30         | V    |
| $V_{GS}$   | Gate-Source Voltage                 | $\pm 20$   | V    |
| $T_J$  | Maximum Junction Temperature        | 150        | °C   |
| $T_{STG}$  | Storage Temperature Range           | -50 to 155 | °C   |
| $I_S$  | Diode Continuous Forward Current    | 350        | A    |
| <b>Mounted on Large Heat Sink</b>                      |                                     |            |      |
| $I_{DM}$   | Pulse Drain Current Tested          | 1400       | A    |
| $I_D$  | Continuous Drain Current            | 350        | A    |
| $P_D$  | Maximum Power Dissipation           | 138        | W    |
| $R_{QJA}$  | Thermal Resistance Junction-Ambient | 40         | °C/W |

## Ordering Information (Example)

| Type      | Package    | Marking       | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|------------|---------------|----------------------|-------------------------|----------------------------|---------------|
| MC0D350AG | PDFN5X6-8L | MC0D350A<br>G | 5,000                | 10,000                  | 70,000                     | 13" reel      |

**Electrical Characteristics (TJ=25°C unless otherwise noted)**

| Symbol  | Parameter                        | Condition   | Min | Typ  | Max  | Unit |
|---|----------------------------------|---|-----|------|------|------|
| <b>Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)</b>  |                                  |   |     |      |      |      |
| BV <sub>(BR)DSS</sub>   | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA  | 30  | --   | --   | V    |
| I <sub>DSS</sub>  | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =30V, V <sub>GS</sub> =0V   | --  | --   | 1    | μA   |
| I <sub>GSS</sub>  | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V  | --  | --   | ±100 | nA   |
| V <sub>GS(th)</sub>   | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                            | 1.0 | --   | 2.5  | V    |
| R <sub>DS(on)</sub>   | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =20A   | --  | 0.5  | 0.8  | mΩ   |
|   |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A  | --  | 1.0  | 1.4  | mΩ   |
| <b>Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)</b> |                                  |   |     |      |      |      |
| C <sub>ISS</sub>  | Input Capacitance                | V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz                                   | --  | 9600 | --   | pF   |
| C <sub>OSS</sub>  | Output Capacitance               |   | --  | 5600 | --   | pF   |
| C <sub>RSS</sub>  | Reverse Transfer Capacitance     |   | --  | 230  | --   | pF   |
| <b>Switching Characteristics</b>  |                                  |   |     |      |      |      |
| Qg  | Total Gate Charge                | V <sub>DS</sub> =15V, I <sub>D</sub> =30A, V <sub>GS</sub> =10V                     | --  | 103  | --   | nC   |
| Qgs   | Gate Source Charge               |   | --  | 22   | --   | nC   |
| Qgd   | Gate Drain Charge                |   | --  | 25   | --   | nC   |
| t <sub>d(on)</sub>  | Turn-on Delay Time               | V <sub>DS</sub> =15V, I <sub>D</sub> =30A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω | --  | 26   | --   | nS   |
| t <sub>r</sub>  | Turn-on Rise Time                |   | --  | 43   | --   | nS   |
| t <sub>d(off)</sub>   | Turn-Off Delay Time              |   | --  | 68   | --   | nS   |
| t <sub>f</sub>  | Turn-Off Fall Time               |   | --  | 35   | --   | nS   |
| <b>Source- Drain Diode Characteristics</b>                                      |                                  |   |     |      |      |      |
| V <sub>SD</sub>   | Forward on voltage               | T <sub>j</sub> =25°C, I <sub>S</sub> =10A   | --  | --   | 1.2  | V    |

### Typical Operating Characteristics

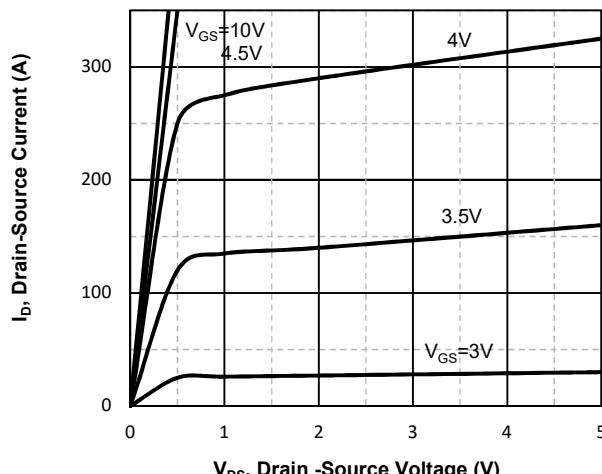


Fig1. Typical Output Characteristics

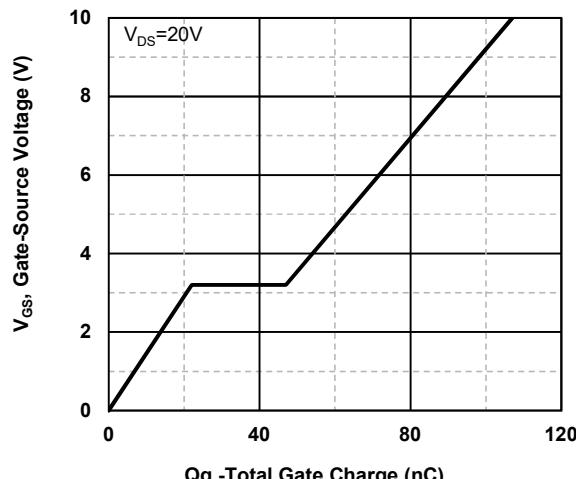


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

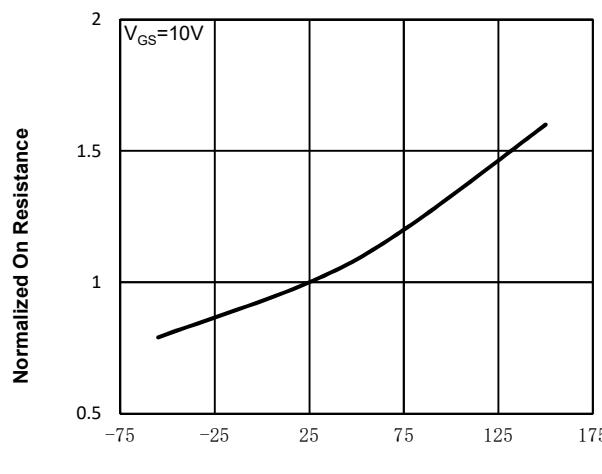


Fig3. Normalized On-Resistance Vs. Temperature

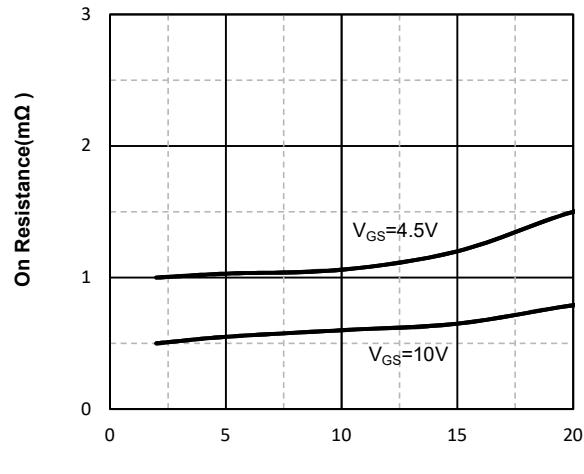


Fig4. On-Resistance Vs. Drain-Source Current

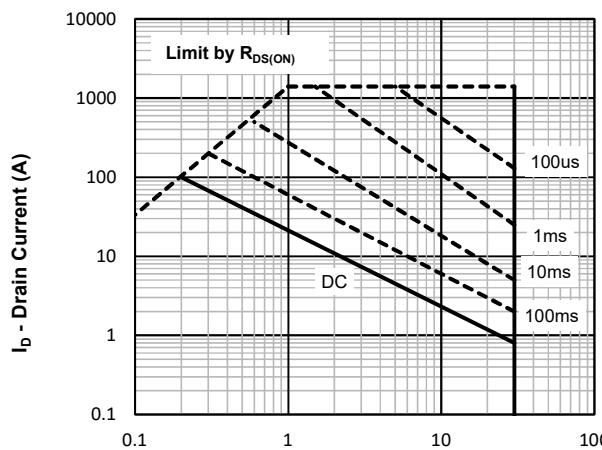


Fig5. Maximum Safe Operating Area

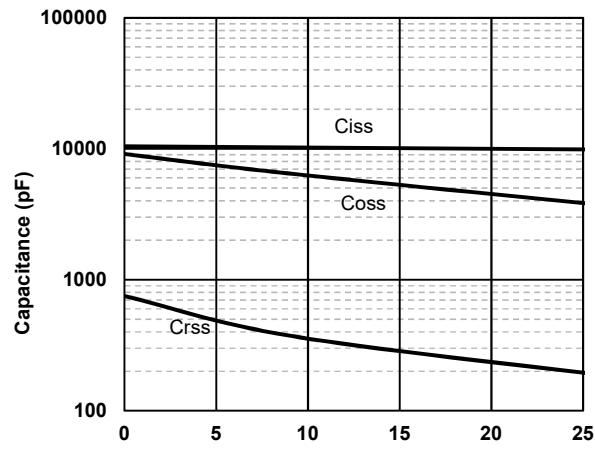
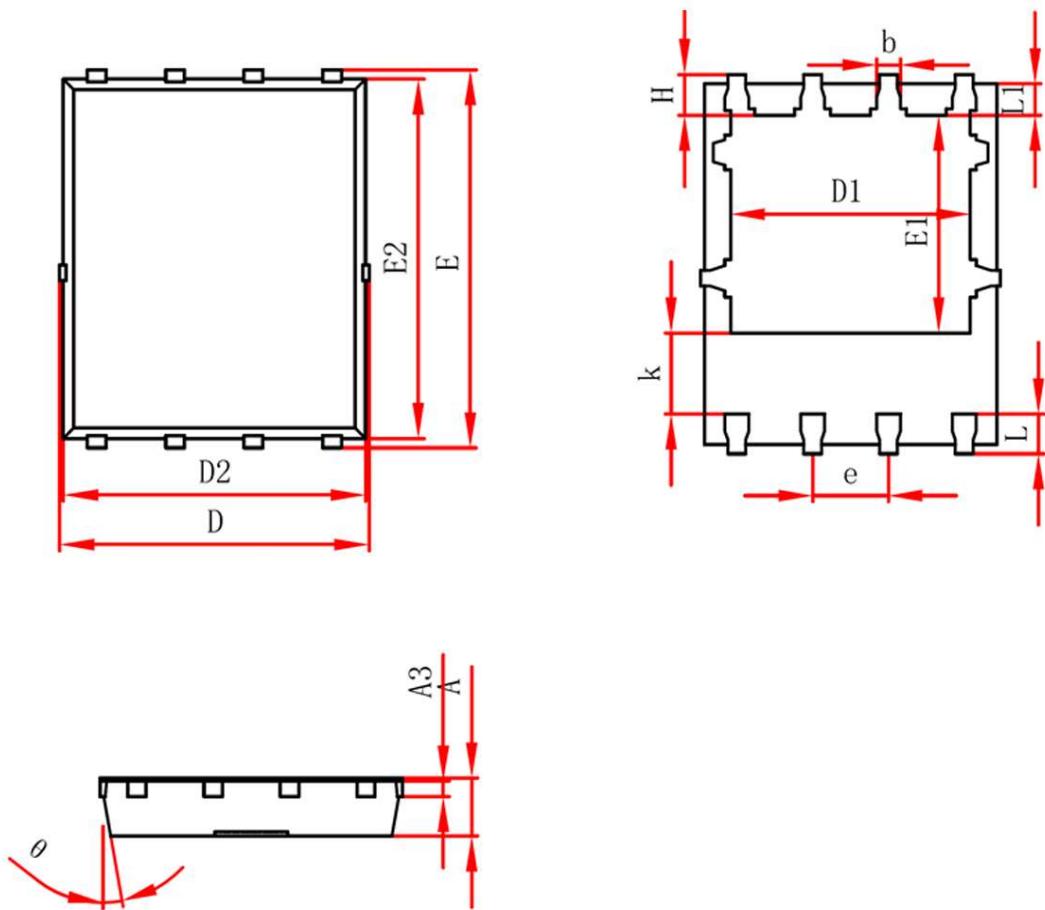


Fig6 Typical Capacitance Vs.Drain-Source

**PDFN5X6-8L Package information**


| Symbol | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 0.950                         | 1.050 | 0.035                | 0.039 |
| A3     | 0.254REF.                     |       | 0.010REF.            |       |
| D      | 4.950                         | 5.050 | 0.196                | 0.200 |
| E      | 5.950                         | 6.050 | 0.235                | 0.239 |
| D1     | 4.026                         | 4.126 | 0.159                | 0.163 |
| E1     | 3.510                         | 3.610 | 0.139                | 0.143 |
| D2     | 4.850                         | 4.950 | 0.192                | 0.196 |
| E2     | 5.700                         | 5.800 | 0.225                | 0.229 |
| k      | 1.190                         | 1.390 | 0.047                | 0.055 |
| b      | 0.300                         | 0.400 | 0.012                | 0.016 |
| e      | 1.270TYP.                     |       | 0.050TYP.            |       |
| L      | 0.559                         | 0.711 | 0.022                | 0.028 |
| L1     | 0.424                         | 0.576 | 0.017                | 0.023 |
| H      | 0.574                         | 0.726 | 0.023                | 0.029 |
| θ      | 10°                           | 12°   | 10°                  | 12°   |